



#### 4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

### **Product Summary**

VBR (MIN)	IPP (MAX)	CI/O (TYP)
5.5V	3A	0.45pF

# **Description**

The D3V3X4U10LPQ is a high-performance device suitable for protecting four high speed I/Os. These devices are assembled in U-DFN2510-10 package and have high ESD surge capability, low ESD clamping voltage and ultra-low capacitance.

### **Applications**

Typically used at high-speed ports such as USB 3.0, USB 3.1, serial ATA, display port.

## **Features and Benefits**

- Clamping Voltage: 6V at 16A IEC61000-4-2
- IEC61000-4-2 (ESD): Air ±8kV, Contact ±8kV
- IEC61000-4-5 (Lightning): 3A (8/20µs)
- 4 Channels of ESD Protection
- Ultra-Low Channel Input Capacitance of 0.45pF Typical
- TLP Dynamic Resistance: 0.3Ω
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The D3V3X4U10LPQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

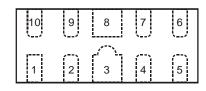
https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

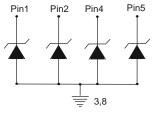
- Case: U-DFN2510-10
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe (Lead Free Plating).
  Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.038 grams (Approximate)

#### U-DFN2510-10

Pin #	Description
1, 2, 4, 5	I/O
6, 7, 9, 10	No Connection
3, 8	Vss



Pin Description (Top View)



Device Schematic

### **Ordering Information** (Note 4)

ĺ	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	D3V3X4U10LPQ-7	Automotive	MU2	7	8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

U-DFN2510-10

MU2 YM

MU2 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

#### Date Code Key

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н		J	K	L	М	N	0	Р	R	S	T
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Condition
Peak Pulse Current, per IEC61000-4-5	IPP	3	Α	I/O to Vss, 8/20µs
Peak Pulse Power, per IEC61000-4-5	P <sub>PP</sub>	18	W	I/O to Vss, 8/20µs
ESD Protection – Contact Discharge, per IEC61000-4-2	VESD_CONTACT	±8	kV	I/O to Vss
ESD Protection – Air Discharge, per IEC61000-4-2	Vesd_air	±8	kV	I/O to Vss

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	P <sub>D</sub>	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	Reja	360	°C/W
Operating and Storage Temperature Range	$T_J$ , $T_{STG}$	-55 to +150	°C

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>	_	_	3.3	V	_
Reverse Current	IR	_	_	1.0	μA	V <sub>R</sub> = 3.3V, I/O to V <sub>SS</sub>
Reverse Breakdown Voltage	$V_{BR}$	5.5	6.2	_	V	$I_R = 1 \text{mA}$ , I/O to $V_{SS}$
Forward Clamping Voltage	VF	-1.0	-0.85	_	V	IF = -15mA, I/O to Vss
Holding Reverse Voltage	VHOLD	_	1.3	_	V	I/O to Vss
Reverse Clamping Voltage (Note 6)	Vc	_	3	_	V	$I_{PP} = 3A$ , I/O to $V_{SS}$ , 8/20 $\mu$ s
Clamping Voltage (Note 7)	Vc	_	6	_	V	TLP, 16A, $t_P = 100$ ns, I/O to $V_{SS}$
Clamping Voltage (Note 7)	Vc	_	5	_	V	TLP, -16A, $t_P$ = 100ns, I/O to $V_{SS}$
Dynamic Reverse Resistance	R <sub>DIF-R</sub>	_	0.3	_	Ω	TLP, 10A, tp = 100ns, I/O to Vss
Dynamic Forward Resistance	R <sub>DIF-F</sub>	_	0.2	_	Ω	TLP, 10A, t <sub>P</sub> = 100ns, V <sub>SS</sub> to I/O
Channel Input Capacitance	C <sub>I/O</sub>	_	0.45	_	pF	$V_{I/O} = 0V$ , $V_{SS} = 0V$ , $f = 1MHz$

Notes:

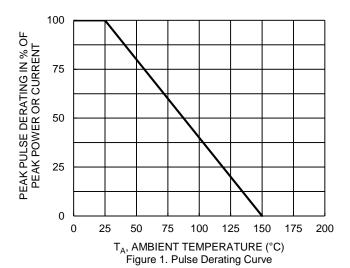
<sup>5.</sup> Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

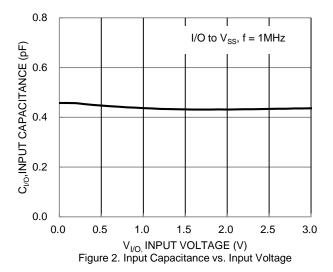
<sup>6.</sup> Clamping voltage value is based on an 8x20µs peak pulse current (IPP) waveform.

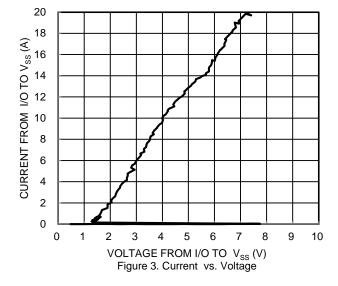
<sup>7.</sup> Clamping voltage value is based on a TLP model. TLP conditions:  $Z_0$ =50 $\Omega$ ,  $t_P$  = 100ns,  $t_P$  = 1ns, averaging window; t1=70ns to t2=90ns.









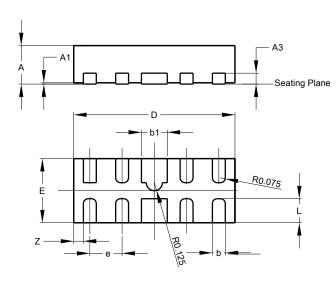




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2510-10

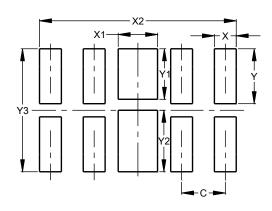


U-DFN2510-10							
Dim	Dim Min Max						
Α	0.545	0.605	0.575				
A1	0.00	0.05	0.03				
A3	-	-	0.13				
b	0.15	0.25	0.20				
b1	0.35	0.45	0.40				
D	2.450	2.575	2.500				
е	-	-	0.50				
Е	0.950	1.075	1.000				
L	0.325	0.425	0.375				
Z	-	-	0.150				
All Dimensions in mm							

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2510-10



Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Y	0.625
Y1	0.575
Y2	0.700
Y3	1.400



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